NSN 5961-01-411-8536

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-411-8536 **Inclosure Material:** Glass **Function For Which Designed:** Rectifier **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 working peak reverse voltage **Current Rating Per Characteristic:** 500.00 milliamperes forward current, average preset and 75.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure:** Demilitarization: No